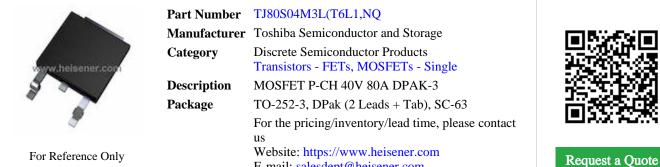


# TJ80S04M3L(T6L1,NQ

# TJ80S04M3L(T6L1,NQ Information



E-mail: salesdept@heisener.com

#### For Reference Only

### **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



#### TJ80S04M3L(T6L1,NQ Specifications

Manufacturer Part Number	TJ80S04M3L(T6L1,NQ
Manufacturer	Toshiba Semiconductor and Storage
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-252-3, DPak (2 Leads + Tab), SC-63
Series	U-MOSVI
FET Type	P-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	40V
Current - Continuous Drain (Id) @ 25°C	80A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	6V, 10V
Vgs(th) (Max) @ Id	3V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	158nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	7770pF @ 10V
Vgs (Max)	+10V, -20V
FET Feature	-
Power Dissipation (Max)	100W (Tc)
Rds On (Max) @ Id, Vgs	5.2 mOhm @ 40A, 10V
Operating Temperature	175°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	DPAK+
Package / Case	TO-252-3, DPak (2 Leads + Tab), SC-63
	Report errors?

### TJ80S04M3L(T6L1,NQ Guarantees



**Quality Guarantees** 

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

DISCOVER

### TJ80S04M3L(T6L1,NQ Payment Methods



## TJ80S04M3L(T6L1,NQ Shipping Methods



If you have any question about TJ80S04M3L(T6L1,NQ, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com